NSN 5962-01-309-8748

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View Online at https://aerobasegroup.com/nsn/5962-01-309-8748

Overall Height:

Between 0.357 inches and 0.432 inches

Body Length:

1.490 inches

Body Width:

Between 0.500 inches and 0.610 inches

Body Height:

Between 0.172 inches and 0.217 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Monolithic and programmable and ultraviolet erasable

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Metal oxide-semiconductor logic

Input Circuit Pattern:

17 input

Case Outline Source And Designator:

D-10 mil-m-38510

Current Rating Per Characteristic:

125.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.6 volts power source and 6.2 volts power source

Time Rating Per Chacteristic:

250.00 nanoseconds af output megawatts

Memory Device Type:

Eprom

Test Data Document:

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

28 printed circuit

Specification Data:

81349-mil-m-38510/224 government specification

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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